

Standard Silicon Rectifiers

Reverse Voltage - 100 to 1000 V

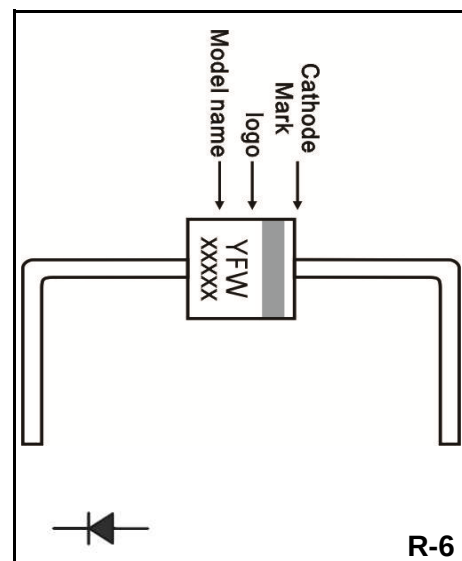
Forward Current - 10 A

FEATURES

- ◆For surface mounted applications
- ◆Open Junction chip
- ◆Low profile package
- ◆Ideal for automated placement
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: R-6
- ◆Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	10A1 MW	10A2 MW	10A4 MW	10A5 MW	10A6 MW	10A8 MW	10A10 MW	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	200	400	500	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	350	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	100	200	400	500	600	800	1000	V
Maximum Average Forward Rectified Current at $T_c = 100\text{ }^{\circ}\text{C}$	$I_{F(AV)}$	10.0							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	400.0							A
Maximum Instantaneous Forward Voltage at 10A	V_F	1.10							V
Maximum DC Reverse Current $T_a = 25\text{ }^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^{\circ}\text{C}$	I_R	10.0 500							μA
Typical Junction Capacitance ⁽¹⁾	C_j	150.0							pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	10.0							$^{\circ}\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150							$^{\circ}\text{C}$

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

FIG. 1- DERATING CURVE OUTPUT RECTIFIED CURRENT

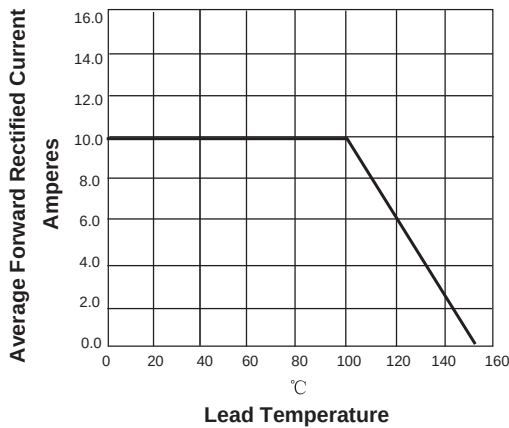


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

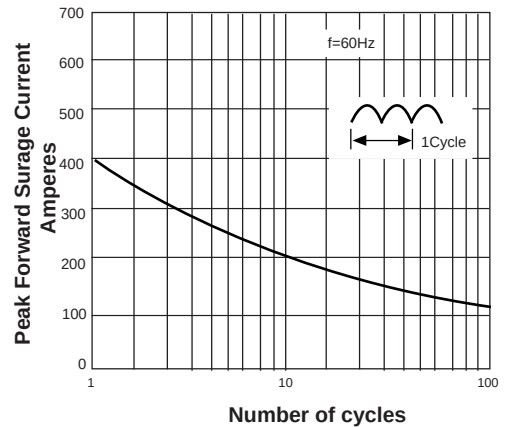


FIG. 3-TYPICAL FORWARD VOLTAGE CHARACTERISTICS

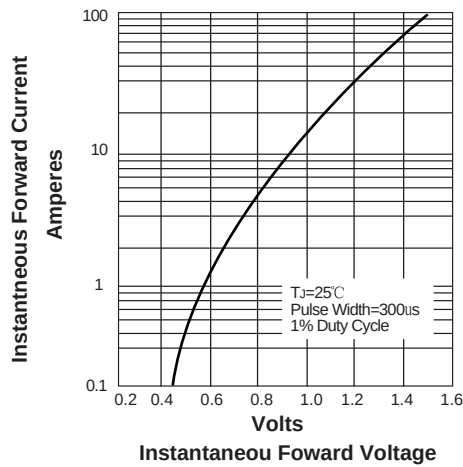
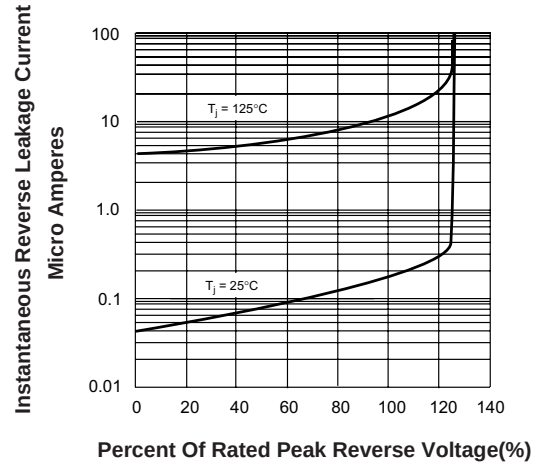


FIG. 4-TYPICAL REVERSE LEAKAGE CHARACTERISTICS



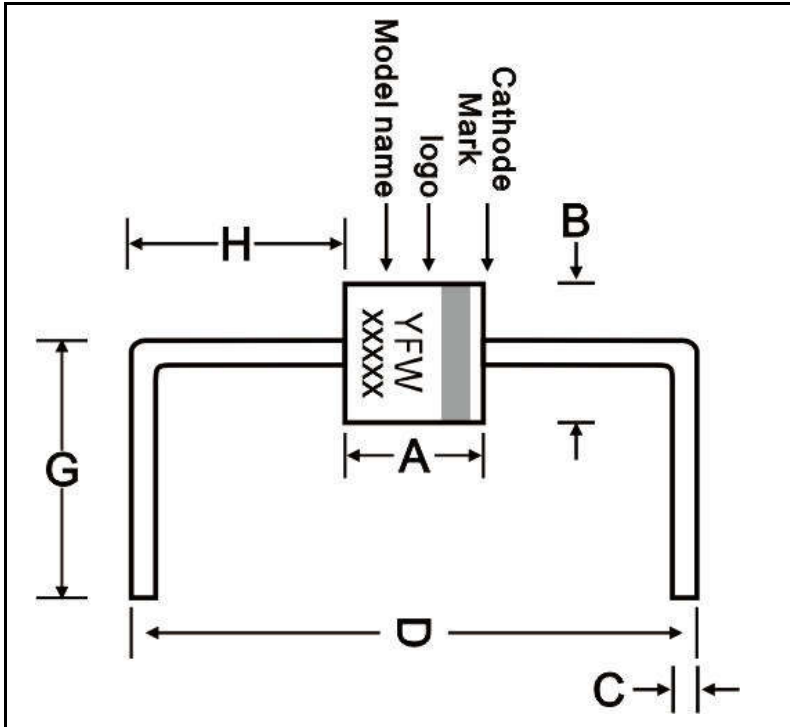
Ordering information

Package	Packing Description	Packing Quantity
R-6	bulk	500pcs/Bag 1000PCS/Box

Package Dimensions

R-6

Dim.	Millimeter(mm)		INCHES	
	Min.	Max.	Min.	Max.
A	8.60	9.10	0.340	0.360
B	8.60	9.10	0.340	0.360
C	1.20	1.30	0.048	0.052
D	18.30	18.80	0.72	0.74
G	7.80	8.50	0.307	0.335
H	3.30	4.00	0.130	0.157



Disclaimer

The information presented in this document is for reference only. Guangdong Youfeng Microelectronics Co.,Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise. The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), YFW or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale. This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <https://www.yfwdiode.com>, or consult YFW sales office for further assistance.